

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# RJK0856DPB

Silicon N Channel Power MOS FET  
Power Switching

REJ03G1885-0100

Rev.1.00

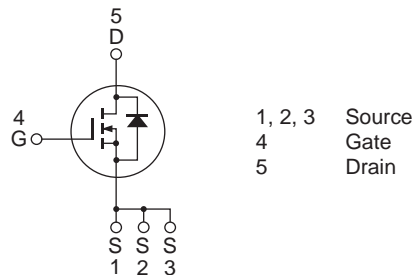
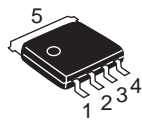
Dec 01, 2009

## Features

- High speed switching
- Low drive current
- Low on-resistance
- $R_{DS(on)} = 6.9 \text{ m}\Omega$  typ. (at  $V_{GS} = 10 \text{ V}$ )
- Pb-free
- Halogen-free
- High density mounting

## Outline

RENESAS Package code: PTZZ0005DA-A  
(Package name: LFPAK)



## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

| Item                                   | Symbol                          | Ratings     | Unit                      |
|--|---------------------------------|-------------|---------------------------|
| Drain to source voltage                | $V_{DSS}$                       | 80          | V                         |
| Gate to source voltage                 | $V_{GSS}$                       | $\pm 20$    | V                         |
| Drain current                          | $I_D$                           | 35          | A                         |
| Drain peak current                     | $I_{D(pulse)}$ <sup>Note1</sup> | 140         | A                         |
| Body-drain diode reverse drain current | $I_{DR}$                        | 35          | A                         |
| Avalanche current                      | $I_{AP}$ <sup>Note 2</sup>      | 35          | A                         |
| Avalanche energy                       | $E_{AR}$ <sup>Note 2</sup>      | 16          | mJ                        |
| Channel dissipation                    | $P_{ch}$ <sup>Note3</sup>       | 65          | W                         |
| Channel to Case Thermal Resistance     | $\theta_{ch-C}$                 | 1.92        | $^\circ\text{C}/\text{W}$ |
| Channel temperature                    | $T_{ch}$                        | 150         | $^\circ\text{C}$          |
| Storage temperature                    | $T_{stg}$                       | -55 to +150 | $^\circ\text{C}$          |

Notes: 1.  $PW \leq 10 \mu\text{s}$ , duty cycle  $\leq 1\%$

2. Value at  $L=10\mu\text{H}$ ,  $T_{ch} = 25^\circ\text{C}$ ,  $R_g \geq 50 \Omega$

3.  $T_c = 25^\circ\text{C}$

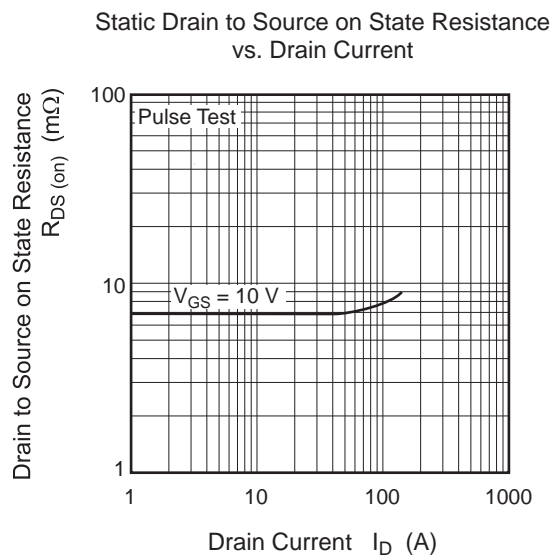
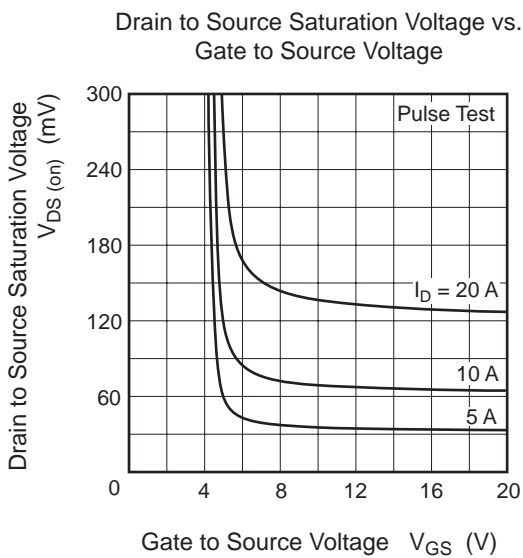
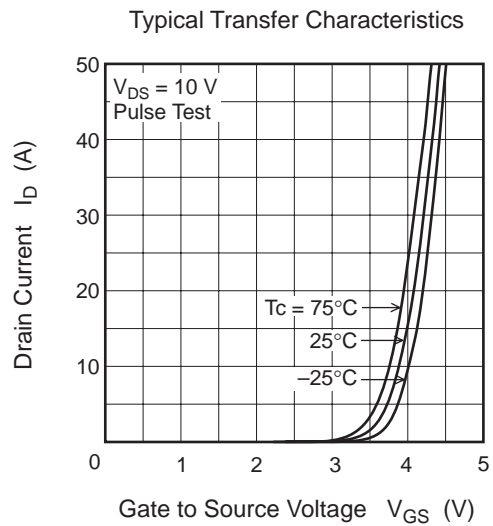
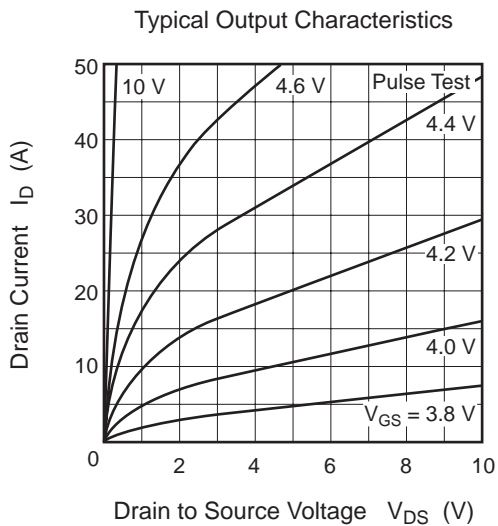
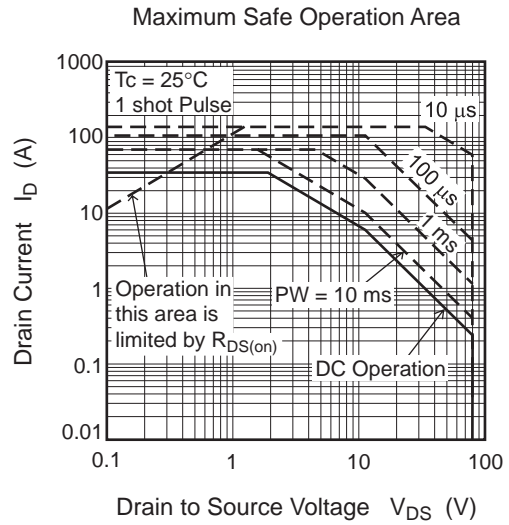
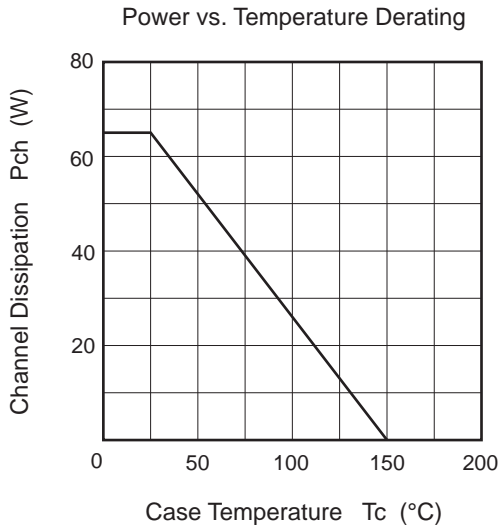
## Electrical Characteristics

(Ta = 25°C)

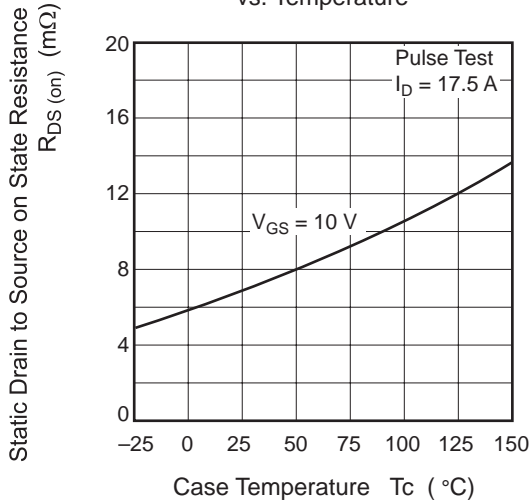
| Item                                       | Symbol        | Min | Typ  | Max       | Unit             | Test Conditions  |
|--|---------------|-----|------|-----------|------------------|--|
| Drain to source breakdown voltage          | $V_{(BR)DSS}$ | 80  | —    | —         | V                | $I_D = 10 \text{ mA}$ , $V_{GS} = 0 \text{ V}$   |
| Gate to source leak current                | $I_{GSS}$     | —   | —    | $\pm 0.1$ | $\mu\text{A}$    | $V_{GS} = \pm 20 \text{ V}$ , $V_{DS} = 0 \text{ V}$   |
| Zero gate voltage drain current            | $I_{DSS}$     | —   | —    | 1         | $\mu\text{A}$    | $V_{DS} = 80 \text{ V}$ , $V_{GS} = 0 \text{ V}$   |
| Gate to source cutoff voltage              | $V_{GS(off)}$ | 2.0 | —    | 4.0       | V                | $V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$   |
| Static drain to source on state resistance | $R_{DS(on)}$  | —   | 6.9  | 8.9       | $\text{m}\Omega$ | $I_D = 17.5 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>  |
| Forward transfer admittance                | $ y_{fs} $    | —   | 53   | —         | S                | $I_D = 17.5 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note4</sup>  |
| Input capacitance                          | $C_{iss}$     | —   | 3000 | —         | pF               | $V_{DS} = 10 \text{ V}$ , $V_{GS} = 0 \text{ V}$ ,<br>$f = 1 \text{ MHz}$  |
| Output capacitance                         | $C_{oss}$     | —   | 585  | —         | pF               |  |
| Reverse transfer capacitance               | $C_{rss}$     | —   | 155  | —         | pF               |  |
| Gate Resistance                            | $R_g$         | —   | 0.5  | —         | $\Omega$         | $V_{DD} = 25 \text{ V}$ , $V_{GS} = 10 \text{ V}$ ,<br>$I_D = 35 \text{ A}$  |
| Total gate charge                          | $Q_g$         | —   | 40   | —         | nC               |  |
| Gate to source charge                      | $Q_{gs}$      | —   | 13   | —         | nC               |  |
| Gate to drain charge                       | $Q_{gd}$      | —   | 7.0  | —         | nC               | $V_{GS} = 10 \text{ V}$ , $I_D = 17.5 \text{ A}$ ,<br>$V_{DD} \cong 30 \text{ V}$ , $R_L = 1.7 \Omega$ ,<br>$R_g = 4.7 \Omega$ |
| Turn-on delay time                         | $t_{d(on)}$   | —   | 16   | —         | ns               |  |
| Rise time                                  | $t_r$         | —   | 7.2  | —         | ns               |  |
| Turn-off delay time                        | $t_{d(off)}$  | —   | 36   | —         | ns               |  |
| Fall time                                  | $t_f$         | —   | 8.6  | —         | ns               | $I_F = 35 \text{ A}$ , $V_{GS} = 0 \text{ V}$ <sup>Note4</sup>   |
| Body-drain diode forward voltage           | $V_{DF}$      | —   | 0.8  | 1.1       | V                |  |
| Body-drain diode reverse recovery time     | $t_{rr}$      | —   | 46   | —         | ns               | $I_F = 35 \text{ A}$ , $V_{GS} = 0 \text{ V}$<br>$di_F/dt = 100 \text{ A}/\mu\text{s}$   |

Notes: 4. Pulse test

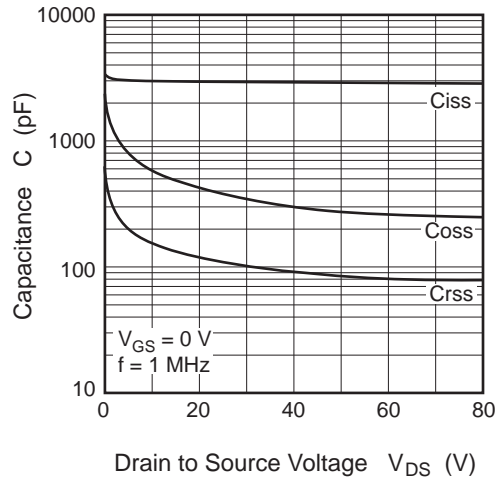
### Main Characteristics



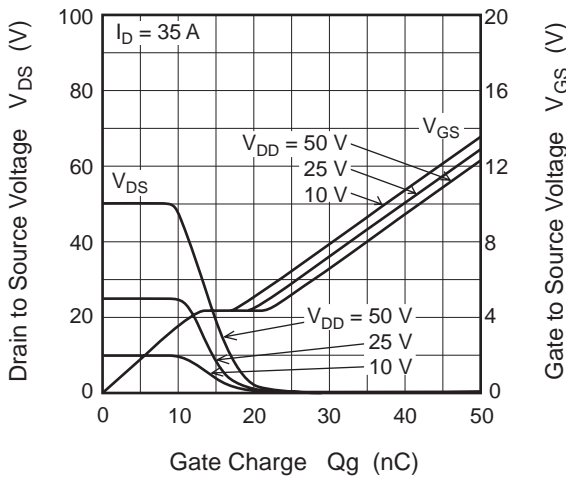
Static Drain to Source on State Resistance vs. Temperature



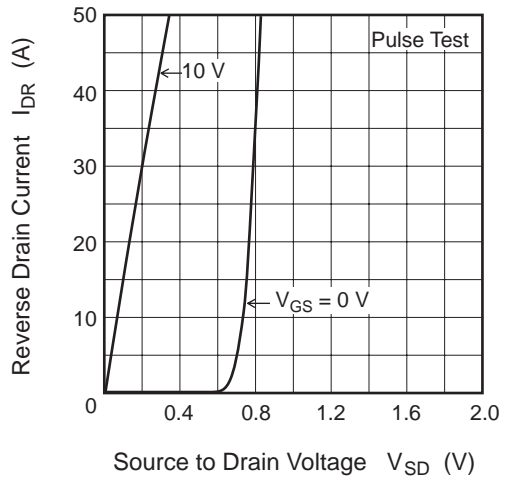
Typical Capacitance vs. Drain to Source Voltage



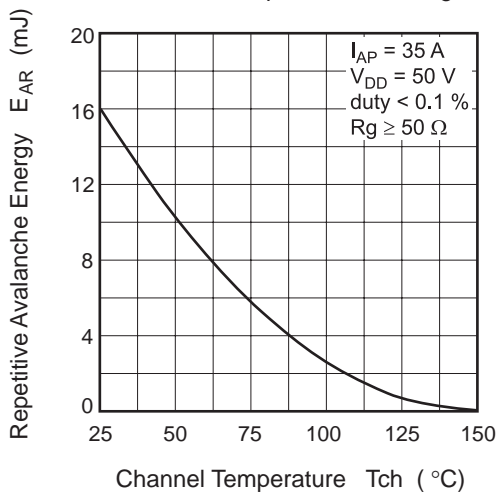
Dynamic Input Characteristics



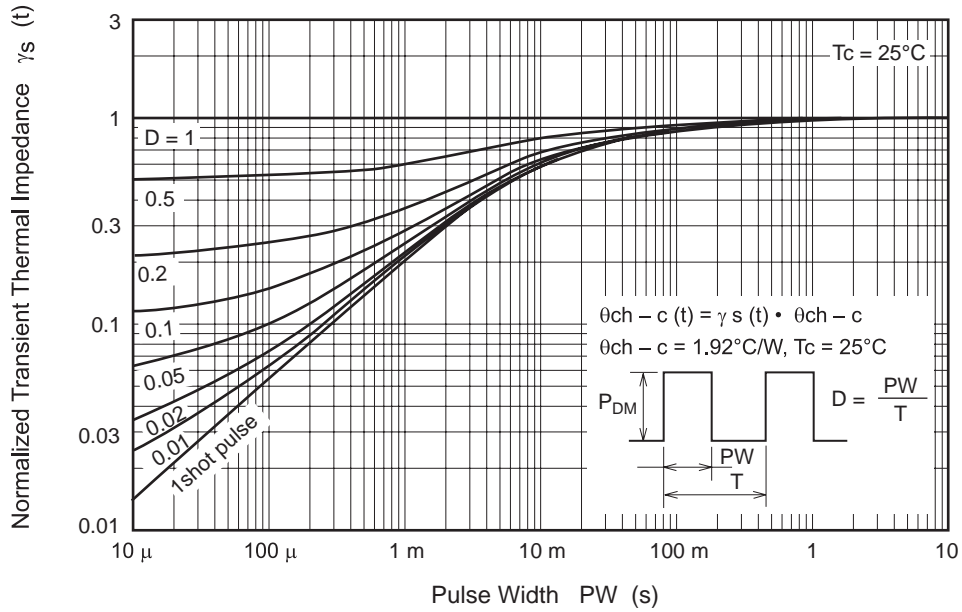
Reverse Drain Current vs. Source to Drain Voltage



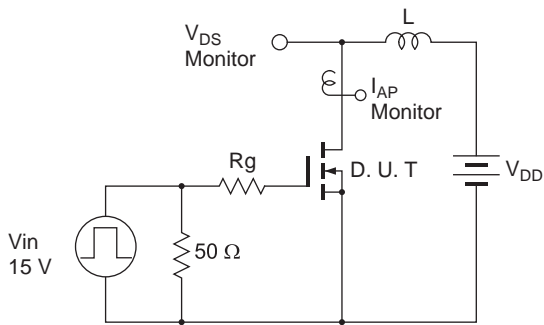
Maximum Avalanche Energy vs. Channel Temperature Derating



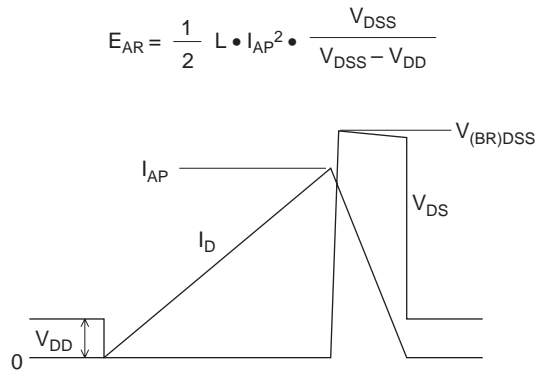
Normalized Transient Thermal Impedance vs. Pulse Width



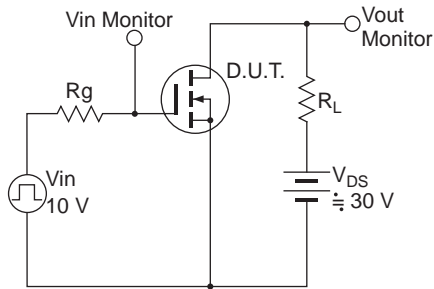
Avalanche Test Circuit



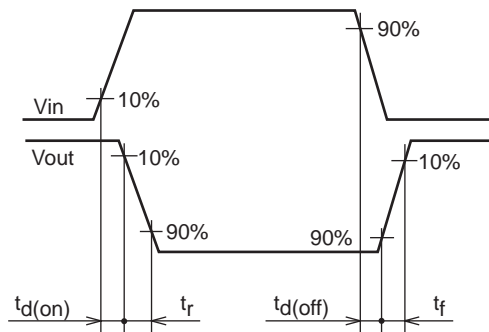
Avalanche Waveform



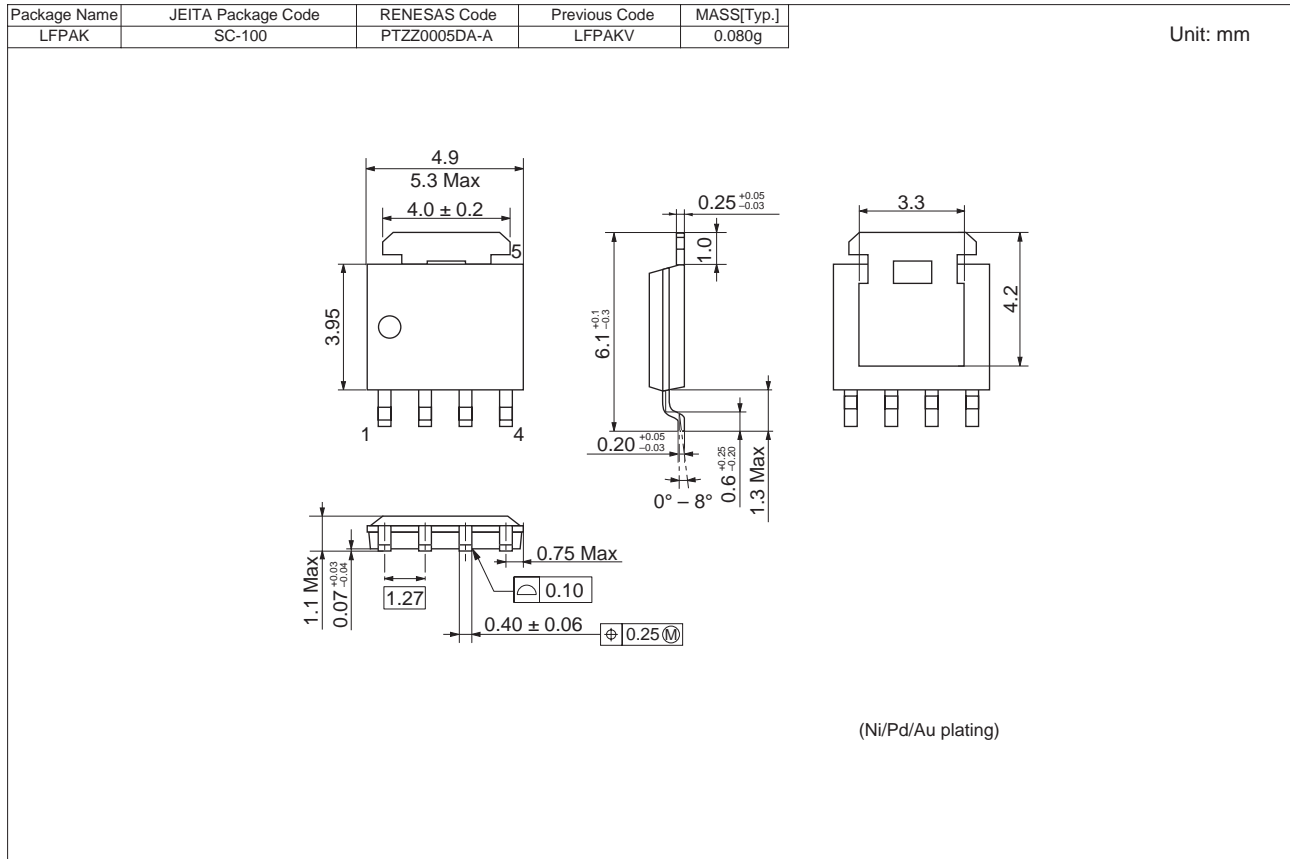
Switching Time Test Circuit



Switching Time Waveform



### Package Dimensions



### Ordering Information

| Part No.         | Quantity | Shipping Container |
|------------------|----------|--------------------|
| RJK0856DPB-00-J5 | 2500 pcs | Taping             |

Notes:

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